

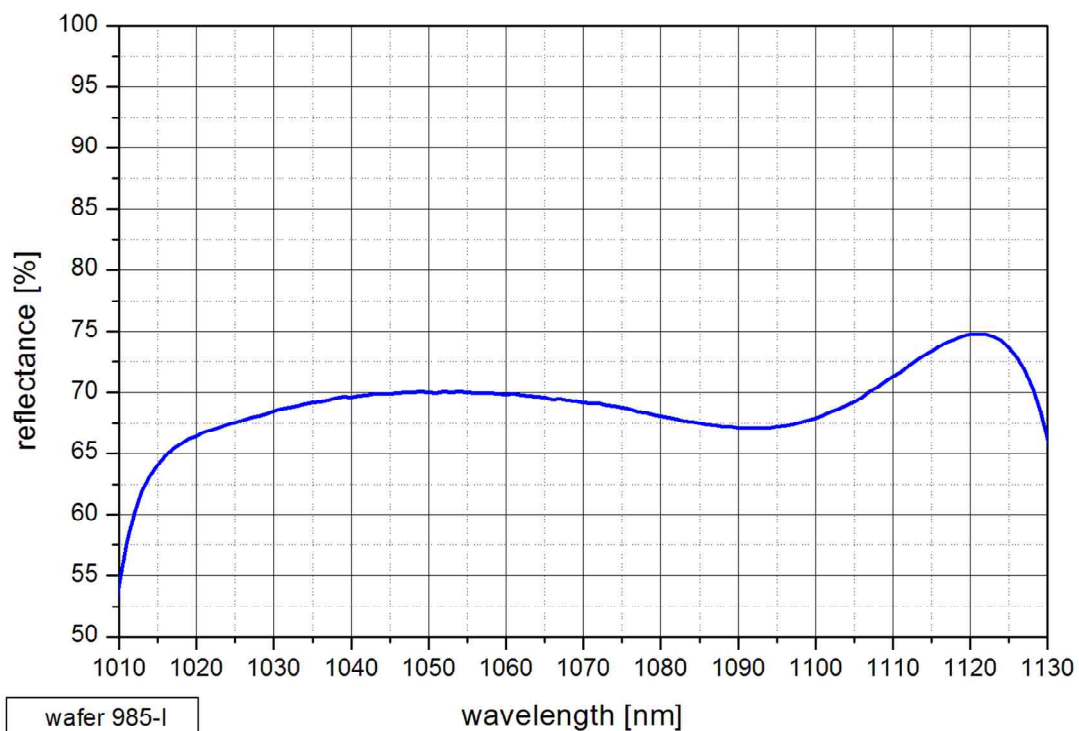
SAM™ Data Sheet SAM-1064-30-25ps-x, $\lambda = 1064 \text{ nm}$

Laser wavelength	$\lambda = 1064 \text{ nm}$
Absorbance	$A_0 = 30 \%$
Modulation depth	$\Delta R = 20 \%$
Non-saturable loss	$A_{ns} = 10 \%$
Saturation fluence	$\Phi_{sat} = 30 \mu\text{J}/\text{cm}^2$
Relaxation time constant	$\tau \sim 25 \text{ ps}$
Damage threshold	$\Phi = 2.5 \text{ mJ}/\text{cm}^2$
Chip area	4.0 mm x 4.0 mm; other dimensions on request
Chip thickness	450 μm
Protection	the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

- x** = 0 unmounted
- x** = 12.7 g glued on a gold plated Cu-cylinder with 12.7 mm \varnothing
- x** = 25.4 g glued on a gold plated Cu-cylinder with 25.4 mm \varnothing
- x** = 12.7 s soldered on a gold plated Cu-cylinder with 12.7 mm \varnothing
- x** = 25.4 s soldered on a gold plated Cu-cylinder with 25.4 mm \varnothing
- x** = FC mounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance



wafer 985-I